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Small Signal MOSFET

250 mA, 200 V, N-Channel TO-92

Features

- AEC-Q101 Qualified and PPAP Capable
- This is a Pb–Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	200	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±30	Vdc Vpk
Drain Current Continuous (Note 1) Pulsed (Note 2)	I _D I _{DM}	250 500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	350	mW
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

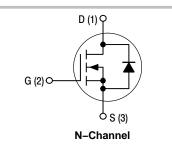


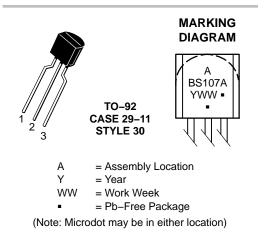
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250 mAMPS, 200 VOLTS

 $R_{DS(on)} = 6.4 \Omega$





ORDERING INFORMATION

Device	Package	Shipping	
BS107ARL1G	TO-92 (Pb-Free)	2000 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Semiconductor Components Industries, LLC, 2014 June, 2014 – Rev. 7

BS107A

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		-	•	•
Zero–Gate–Voltage Drain Current (V_{DS} = 130 Vdc, V_{GS} = 0)	I _{DSS}	-	-	30	nAdc
Drain–Source Breakdown Voltage (V_{GS} = 0, I_D = 100 µAdc)	V _{(BR)DSX}	200	-	-	Vdc
Gate Reverse Current (V _{GS} = 15 Vdc, V _{DS} = 0)	I _{GSS}	_	0.01	10	nAdc
ON CHARACTERISTICS (Note 3)					
Gate Threshold Voltage (I_D = 1.0 mAdc, V_{DS} = V_{GS})	V _{GS(Th)}	1.0	-	3.0	Vdc
Static Drain–Source On Resistance BS107 ($V_{GS} = 2.6$ Vdc, $I_D = 20$ mAdc) ($V_{GS} = 10$ Vdc, $I_D = 200$ mAdc) BS107A ($V_{GS} = 10$ Vdc)	r _{DS(on)}	-		28 14	Ω
$(I_D = 100 \text{ mAdc})$ $(I_D = 250 \text{ mAdc})$		-	4.5 4.8	6.0 6.4	
SMALL-SIGNAL CHARACTERISTICS					
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{iss}	-	60	-	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C _{rss}	-	6.0	-	pF
Output Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C _{oss}	-	30	-	pF
Forward Transconductance $(V_{DS} = 25 \text{ Vdc}, I_D = 250 \text{ mAdc})$	9 _{fs}	200	400	-	mmhos
SWITCHING CHARACTERISTICS					
Turn–On Time	t _{on}	-	6.0	15	ns
Turn-Off Time	t _{off}	-	12	15	ns

3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

RESISTIVE SWITCHING

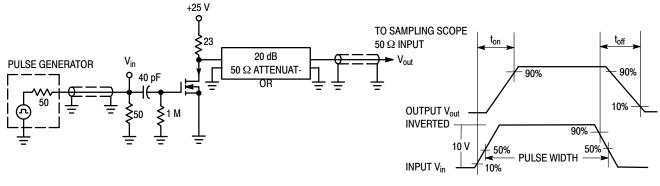
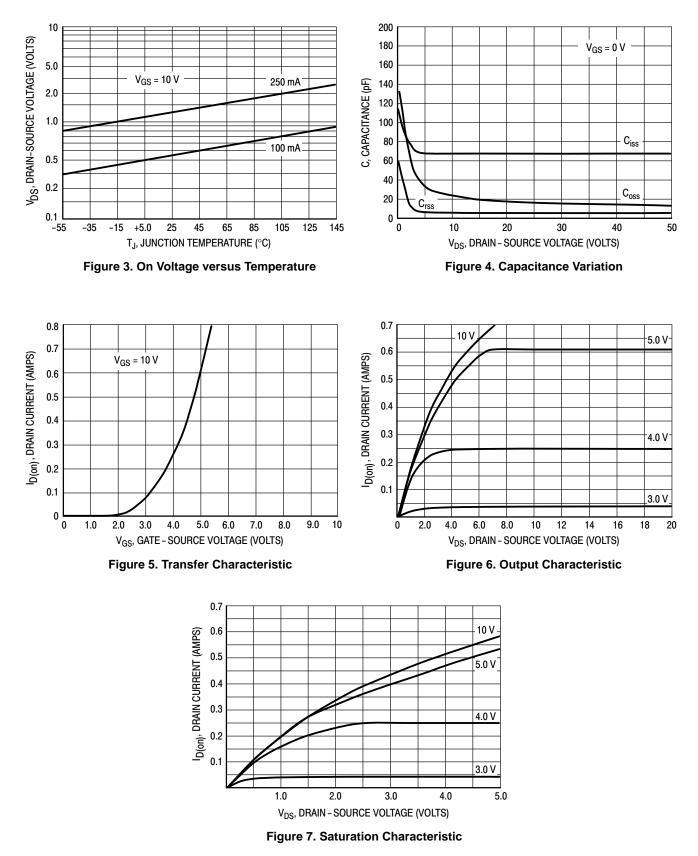


Figure 1. Switching Test Circuit

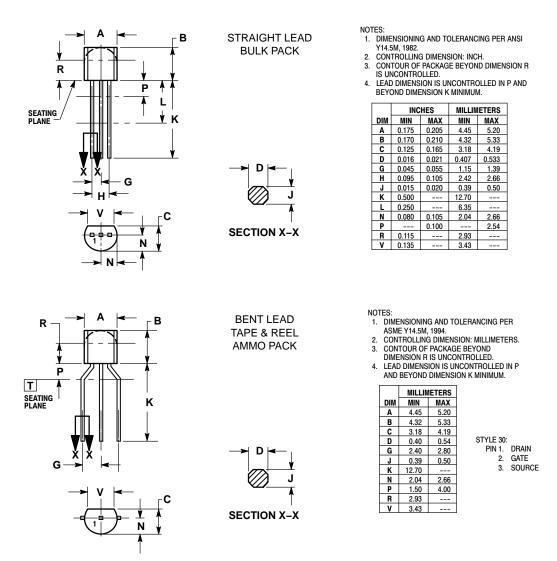
Figure 2. Switching Waveforms



BS107A

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



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